



Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
60V	14mΩ @ V _{GS} = 10V	9.5
000	21mΩ @ V _{GS} = 4.5V	7.7

Description and Applications

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- DC-DC Converter
- Adaptor Switch
- Wireless Charging

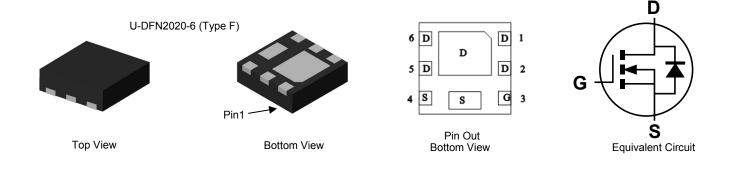
60V N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- 100% Unclamped Inductive Switching (UIS) Test in Production— Ensures More Reliable and Robust End Application
- 0.6mm Profile—Ideal for Low Profile Applications
- PCB Footprint of 4mm²
- Low On-Resistance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: U-DFN2020-6 (Type F)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @
- Weight: 0.007 grams (Approximate)



Ordering Information (Note 4)

Notes:

Part Number	Package	Quantity per Reel
DMT6012LFDF-7	U-DFN2020-6 (Type F)	3000
DMT6012LFDF-13	U-DFN2020-6 (Type F)	10,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

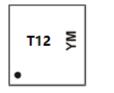
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

Site 1:



T12 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Kev

Year	2017	201	8	2019	2020	202	:1	2022	2023	202	24	2025
Code	E	F		G	Н			J	K	L		М
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

Site 2:



T12 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 0 = 2020)W = Week (ex: a = week 27; z represents week 52 and 53) X = Internal code (ex: U = Monday)

Date	Code	Kev
Daic	Ouuc	T\Cy

Year	2017	2018	2019	2020	2021	2022	2023	2024	2025
Code	7	8	9	0	1	2	3	4	5
Week		1-26			27-52			53	
Code		A-Z			a-z z				
Internal Code	Sun	Mo	n	Tue	Wed	Thu		Fri	Sat
Code	Т	U		V	W	Х		Y	Z



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V _{DSS}	60	V
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current (Note 6) V_{GS} = 10V	ID	9.5 7.6	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	60	A
Maximum Body Diode Continuous Current		Is	2.1	A
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle =	1%)	I _{SM}	60	А
Avalanche Current (Note 7) L = 0.1mH	I _{AS}	12.6	А	
Avalanche Energy (Note 7) L = 0.1mH		E _{AS}	7.9	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit	
Total Dower Dissinction (Note 5)	T _A = +25°C	D	0.9	W	
Total Power Dissipation (Note 5)	T _A = +70°C	PD	0.6	vv	
Thermal Resistance, Junction to Ambient (Note 5)		R _{OJA}	131	°C/W	
Tatal Dawar Dissination (Nata 6)	T _A = +25°C	D	1.9	W	
Total Power Dissipation (Note 6)	T _A = +70°C	PD	1.2	vv	
Thermal Resistance, Junction to Ambient (Note 6)		R _{OJA}	66	°C/W	
Total Power Dissipation (Note 6)	T _C = +25°C	PD	11	W	
Thermal Resistance, Junction to Case (Note 6)		R _{eJC}	11.4	°C/W	
Operating and Storage Temperature Range		T _{J.} T _{STG}	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV _{DSS}	60	—	_	V	V _{GS} = 0V, I _D = 250µA
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	$V_{DS} = 48V, V_{GS} = 0V$
Gate-Source Leakage	Igss	_	_	±100	nA	V_{GS} = ±20V, V_{DS} = 0V
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(TH)}	1.2	_	2.3	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Static Drain-Source On-Resistance		_	10.7	14	mΩ	V _{GS} = 10V, I _D = 8.5A
Static Drain-Source On-Resistance	R _{DS(ON)}	—	15.7	21	11152	V_{GS} = 4.5V, I_{D} = 6A
Diode Forward Voltage	V _{SD}	_	0.7	1.2	V	V _{GS} = 0V, I _S = 1A
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss		785			V _{DS} = 30V, V _{GS} = 0V f = 1MHz
Output Capacitance	Coss		281		pF	
Reverse Transfer Capacitance	Crss	—	27			
Gate Resistance	Rg	_	1.5		Ω	V_{DS} = 0V, V_{GS} = 0V, f = 1MHz
Total Gate Charge (V _{GS} = 4.5V)	Qg	—	7.3			
Total Gate Charge (V _{GS} = 10V)	Qg	_	13.6		nC	V _{DS} = 30V. I _D = 10A
Gate-Source Charge	Q _{gs}	_	2.2	_	110	$v_{DS} = 30v$, $i_D = 10A$
Gate-Drain Charge	Q _{gd}	_	3.4	_		
Turn-On Delay Time	t _{D(ON)}	_	3.2			
Turn-On Rise Time	t _R		4.4		ns	V _{GS} = 10V, V _{DD} = 30V,
Turn-Off Delay Time	t _{D(OFF)}		14.7		115	$R_g = 6\Omega, I_D = 10A$
Turn-Off Fall Time	t _F		8.5			
Body Diode Reverse Recovery Time	t _{RR}		23.0		ns	
Body Diode Reverse Recovery Charge	Q _{RR}	_	14.1		nC	I _F = 10A, di/dt = 100A/μs

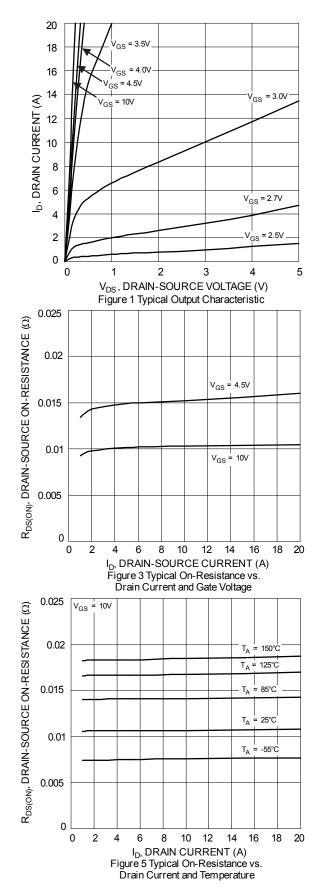
5. Device mounted on FR-4 substrate PCB, 2oz copper, with minimum recommended pad layout. Notes:

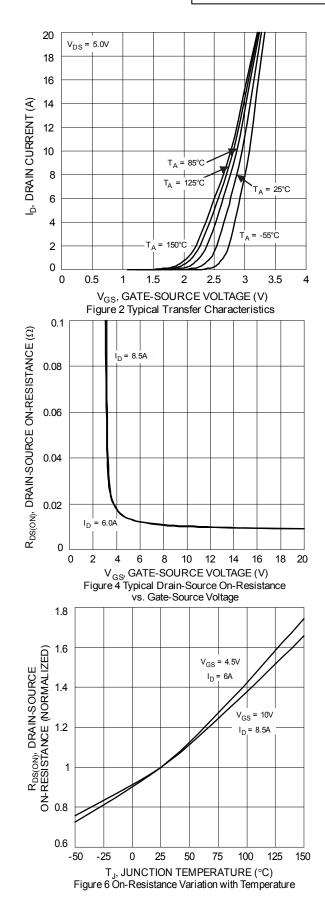
6. Device mounted on FR-4 substrate PCB, 2oz copper, with 1inch square copper plate.

7. J_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$. 8. Short duration pulse test used to minimize self-heating effect. 9. Guaranteed by design. Not subject to product testing.

Downloaded From Oneyac.com

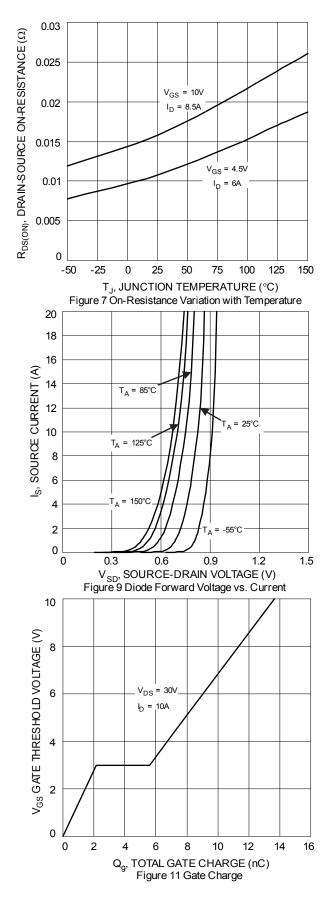


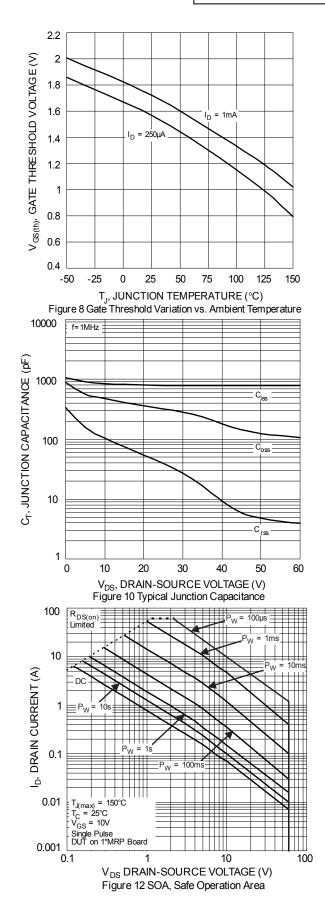




DMT6012LFDF Datasheet number: DS41142 Rev. 4 - 2

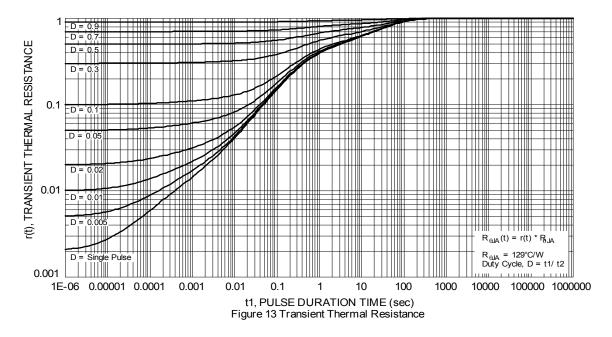






DMT6012LFDF Datasheet number: DS41142 Rev. 4 - 2

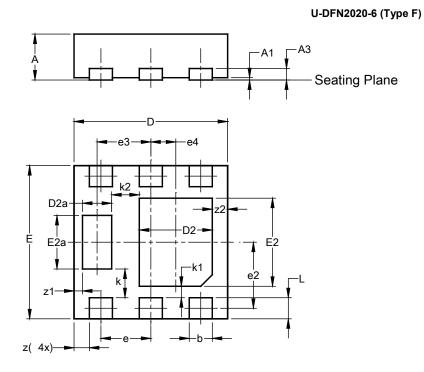






Package Outline Dimensions

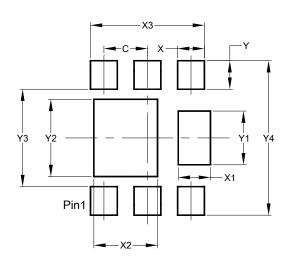
Please see http://www.diodes.com/package-outlines.html for the latest version.



	U-DFN2020-6						
		be F)					
Dim	Min Max Typ						
Α	0.57	0.63	0.60				
A1	0.00	0.05	0.03				
A3	_		0.15				
b	0.25	0.35	0.30				
D	1.95	2.05	2.00				
D2	0.85	1.05	0.95				
D2a	0.33	0.43	0.38				
E	1.95	2.05	2.00				
E2	1.05	1.25	1.15				
E2a	0.65	0.75	0.70				
е	0.65 BSC						
e2	0.863 BSC						
e3		0.70 BS					
e4).325 BS					
k		0.37 BS					
k1	0.15 BSC						
k2	0.36 BSC						
L		0.325					
z		0.20 BS	-				
z1	().110 BS	SC				
z2		0.20 BS	С				
All C)imens	ions in	mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value		
	(in mm)		
С	0.650		
X	0.400		
X1	0.480		
X2	0.950		
X3	1.700		
Y	0.425		
Y1	0.800		
Y2	1.150		
Y3	1.450		
Y4	2.300		

U-DFN2020-6 (Type F)



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2020, Diodes Incorporated

www.diodes.com

单击下面可查看定价,库存,交付和生命周期等信息

>>Diodes Incorporated(达迩科技(美台))